

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LB11685AV —

Monolithic Digital IC 3-phase sensor

3-phase sensor less Motor driver

Overview

The LB11685AV is a three-phase full-wave current-linear-drive motor driver IC. It adopts a sensor less control system without the use of a Hall Effect device. For quieter operation, the LB11685AV features a current soft switching circuit and be optimal for driving the cooling fan motors used in refrigerators, etc.

Functions

- Three-phase full-wave linear drive (Hall sensor-less method)
- Built-in three-phase output voltage control circuit
- Built-in current limiter circuit
- Built-in motor lock protection circuit
- Motor lock protection detection output
- FG output made by back EMF
- Built-in thermal shut down circuit
- Beat lock prevention circuit

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		19	V
Input applied voltage	V _{IN} max		-0.3 to V _{CC} +0.3	V
Maximum output current	I _O max *1		1.2	А
Allowable power dissipation	Pd max	Mounted on a board *2	1.05	W
Operating temperature	Topr		-40 to 85	°C
Storage temperature	Tstg		-55 to 150	°C
Junction temperature	Tj max		150	°C

*1: The I_O is a peak value of motor-current.

*2: Specified board: 76.1mm × 114.3mm × 1.6mm, glass epoxy board.

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Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended Supply voltage	V _{CC}		12.0	V
Operating supply voltage	V _{CC} op		4.5 or 18.0	V

Electrical Characteristics at $Ta = 25^{\circ}C$, $V_{CC} = 5.0V$

Parameter	Symbol	Conditions		Ratings		Unit
Falameter	Symbol	Conditions	min	typ	max	Unit
Supply current	ICC	FC1 = FC2 = 0V	5	10	20	mA
Internal regulate voltage	VREG		3.0	3.3	3.6	V
Output voltage (source)	VOSOUR	I _O = 0.8A *3		1.3	1.7	V
Output voltage (sink)	VOSINK	I _O = 0.8A *3		0.5	1.3	V
Current limiter	VOLIM		0.268	0.300	0.332	V
MCOM pin common-input voltage range	VINCOM		0		V _{CC} - 2	V
MCOM pin Source current for hysteresis	ICOM+	MCOM = 7V	30		80	μA
MCOM pin Sink current for hysteresis	ICOM-	MCOM = 7V	30		80	μΑ
MCOM pin hysteresis current ratio	RTCOM	RTCOM = ICOM+ / ICOM-	0.6		1.4	
VCO input bias current	IVCO	$V_{CO} = 2.3 V$			0.2	μA
VCO oscillation minimum frequency	f _{VCO} min	V _{CO} = 2.1V, CX = 0.015µF Design target *2		930		Hz
VCO oscillation maximum frequency	f _{VCO} max	V _{CO} = 2.7V, CX = 0.015µF Design target *2		8.6		kHz
CX charge / discharge current	ICX	V _{CO} = 2.5V, CX = 1.6V	70	100	140	μΑ
CX hysteresis voltage	ΔVCX		0.35	0.55	0.75	
C1 (C2) charge current	IC1(2)+	V _{CO} = 2.5V, C1(2) = 1.3V	12	20	28	μA
C1 (C2) discharge current	IC1(2)-	V _{CO} = 2.5V, C1(2) = 1.3V	12	20	28	μA
C1 (C2) charge / discharge current ratio	RTC1(2)	RTC1(2) = IC1(2)+ / IC1(2)-	0.8	1.0	1.2	
C1/C2 charge current ratio	RTCCHG	RTCCHG = IC1+ / IC2+	0.8	1.0	1.2	
C1/C2 discharge current ratio	RTCDIS	RTCDIS = IC1- / IC2-	0.8	1.0	1.2	
C1 (C2) cramp voltage width	VCW1(2)		1.0	1.3	1.6	V
FG output low level voltage	VFGL	IFG = 3mA			0.5	V
RD output low level voltage	VRDL	IRD = 3mA			0.5	v
Thermal shut down operating temperature *1	TTSD	Junction temperature Design target *2	150	180		°C
Thermal shut down hysteresis temperature *1	ΔTTSD	Junction temperature Design target *2		15		°C

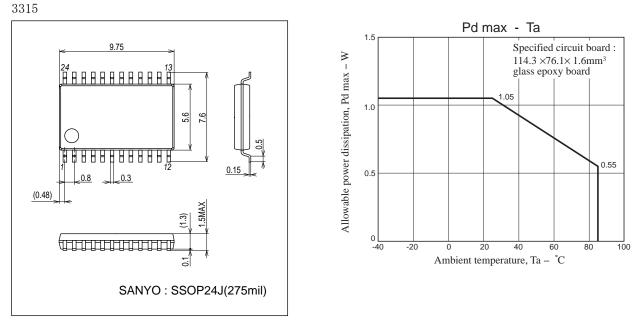
*1: The thermal shut down circuit is built-in for protection from damage of IC. But its operation is out of Topr. Design thermal calculation at normal operation.

*2: Design target value and no measurement is made.

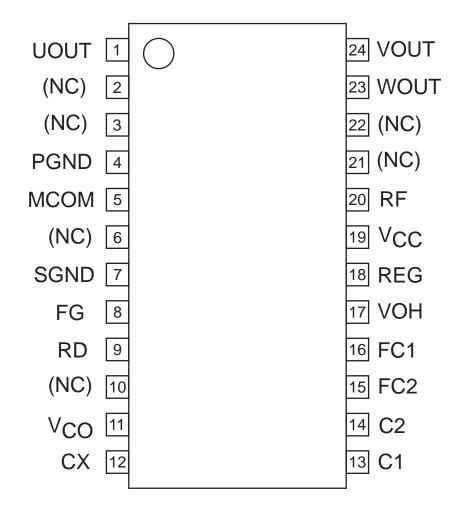
*3: The I_{O} is a peak value of motor-current.

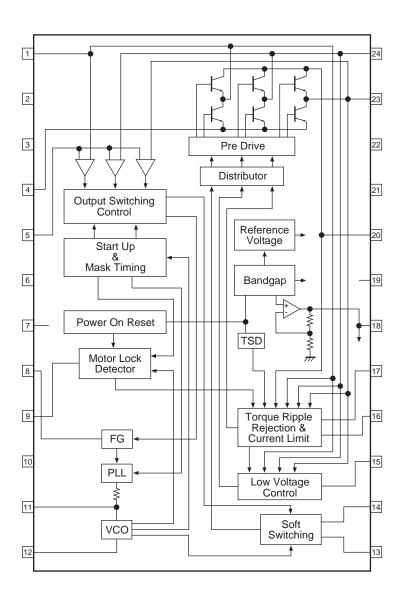
Package Dimensions

unit : mm (typ)



Pin Assignment





Pin Function

Pin No.	Pin name	Function	Equivalent circuit
1	UOUT	Each output pin of three phases.	
23	WOUT		Pin No.20
24	VOUT		•
4	PGND	GND pin in the output part.	
-	1 GIVE	This pin is connected to GND. The SGND pin is also	
		connected to GND	Pin No.1,23,24
20	RF		
20	ĸŗ	Pin to detect output current.	
		By connecting a resistor between this pin and V_{CC} , the	Pin No.4
		output current is detected as a voltage.	
		The current limiter is operated by this voltage.	
5	MCOM	Motor coil midpoint input pin.	
		The coil voltage waveform is detected based on this	
		voltage.	
			SGND SGND SGND
			V _{CC} TV _{CC}
			Pin No.5 🗌 🗍 🗰
			SGND SGND
7	SGND	Ground pin (except the output part)	
		This pin is connected to GND.	
		The PGND pin is also connected to GND.	
8	FG	FG out made by back EMF pin.	
		It synchronizes FG out with inverted V-phase.	
		When don't use this function, open this pin.	Pin No.8
9	RD	Motor lock protection detection output pin.	SGND -O
		Output with L during rotation of motor.	SGND
		Open during lock protection of motor (High-impedance).	2010
		When don't use this function, open this pin.	
11	VCO	PLL output pin and VCO input pin.	
		To stabilize PLL output, connect a capacitor between this	
		pin and GND.	VREG
			V _{CC} + A
			Pin No.11
			भिर्मे के
			SGND — I I I I I I I I I I I I I I I I I I
12	сх	VCO oscillation output pin.	
	-	Operation frequency range and minimum frequency are	
		determined by the capacity of the capacitor connected to	VREG
		this pin.	\prec
			Pin No.12

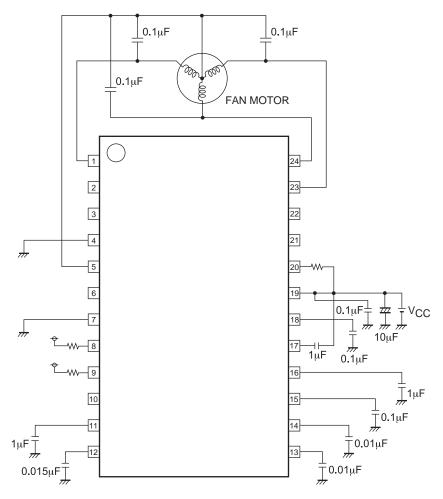
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Pin No.	from the former page. Pin name	Function	Equivalent circuit
13 14	C1 C2	Soft switching adjustment pin. The triangular wave from is form formed by connecting a capacitor with this pin. And, the switching of three-phase output is adjusted by the slope.	Pin No.13
15	FC2	Frequency characteristic correction pin 2. To suppress the oscillation of control system closed loop of sink-side, connect a capacitor between this pin and GND.	Pin No.15
16	FC1	Frequency characteristic correction pin 1. To suppress the oscillation of control system closed loop of source-side, connect a capacitor between this pin and GND.	Pin No.16
17	VOH	Three-phase output high level output pin. To stabilize the output voltage of this pin, connect a capacitor between this pin and the V _{CC} pin.	Pin No.17
18	VREG	DC voltage (3.3V) output pin. Connect a capacitor between this pin and GND for stabilization.	Pin No.18
19	VCC	Pin to supply power-supply voltage. To curb the influence of ripple and noise. The voltage should be stabilized.	

Application Circuit Example

* Each fixed number in the following FIG, is the referential value.



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